NSN 5961-01-253-3417

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View Online at https://aerobasegroup.com/nsn/5961-01-253-3417 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Zzzy **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -100.0 drain to gate voltage **Current Rating Per Characteristic:** -12.00 amperes drain current **Power Rating Per Characteristic:** 75.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 165.0 degrees celsius junction **Special Features:** Item must comply with requirements of defense supply center columbus production standard no. Lo3671 **Terminal Type And Quantity:** 2 pin and 1 case **Reference Number Differentiating Characteristics:** Reference number differentiating material will be in accordance with naval inventory control point activity hx quality control. Manufacturing and testing specifications available at the dla icp Shelf Life:

N/a

Unit Of Measure:

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